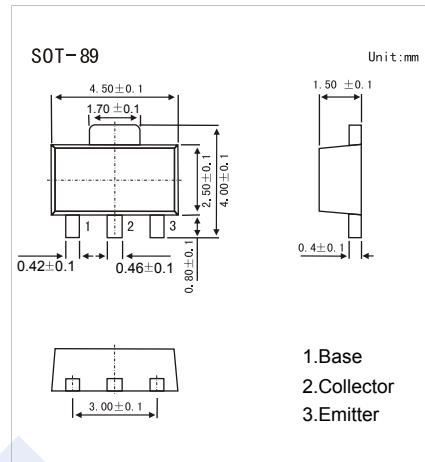
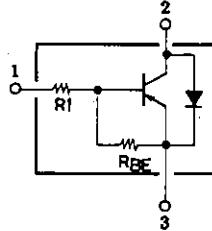


## PNP Transistors

### 2SB1394-HF

#### ■ Features

- Contains diode between collector and emitter.
- Low saturation voltage.
- Large current capacity.
- Complementary to 2SD2099-HF
- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish



#### ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V <sub>CBO</sub>	-40	V
Collector - Emitter Voltage	V <sub>C EO</sub>	-30	
Emitter - Base Voltage	V <sub>EBO</sub>	-6	
Collector Current - Continuous	I <sub>C</sub>	-3	A
Collector Current - Pulse	I <sub>CP</sub>	-5	
Collector Power Dissipation	P <sub>C</sub>	1.5	W
Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature range	T <sub>stg</sub>	-55 to 150	

#### ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V <sub>CBO</sub>	I <sub>C</sub> = -100 μA, I <sub>E</sub> =0	-40			V
Collector-emitter breakdown voltage	V <sub>C EO</sub>	I <sub>C</sub> = -10 mA, R <sub>BE</sub> =∞	-30			
Emitter-base breakdown voltage	V <sub>EBO</sub>	I <sub>E</sub> = -100 μA, I <sub>C</sub> =0	-6			
Collector-base cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -35 V, I <sub>E</sub> =0			-1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -5V, I <sub>C</sub> =0			-0.1	
Collector-emitter saturation voltage	V <sub>C E(sat)</sub>	I <sub>C</sub> =-1 A, I <sub>B</sub> =-50mA			-0.3	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =-1 A, I <sub>B</sub> =-50mA			-1.2	
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> = -2V, I <sub>C</sub> = -500mA	70			
	h <sub>FE(2)</sub>	V <sub>CE</sub> = -2V, I <sub>C</sub> = -2 A	50			
Base-to-Emitter Resistance	R <sub>BE</sub>			0.8		kΩ
Base Resistance	R <sub>1</sub>		60		120	Ω
Diode Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =500mA			1.5	V
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10V, I <sub>E</sub> = 0, f=1MHz		55		pF
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = -2V, I <sub>C</sub> = -500mA		100		MHz

#### ■ Marking

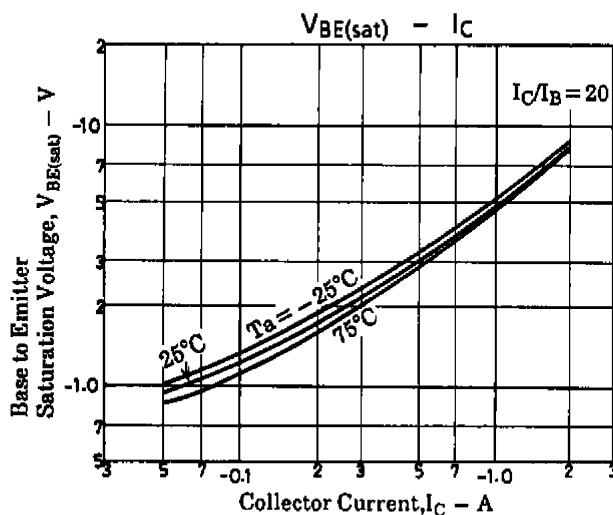
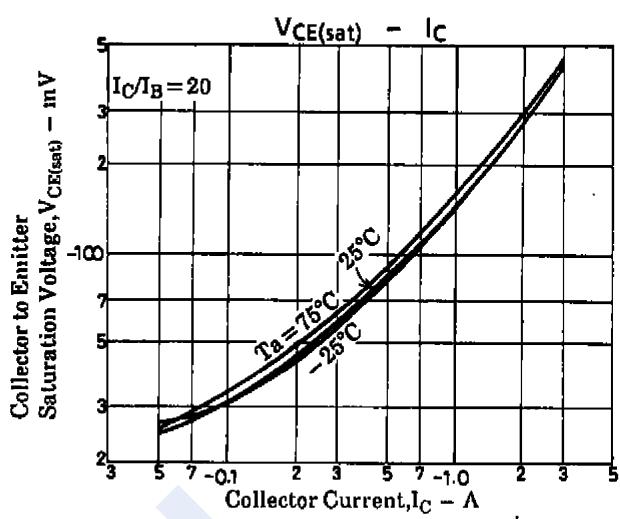
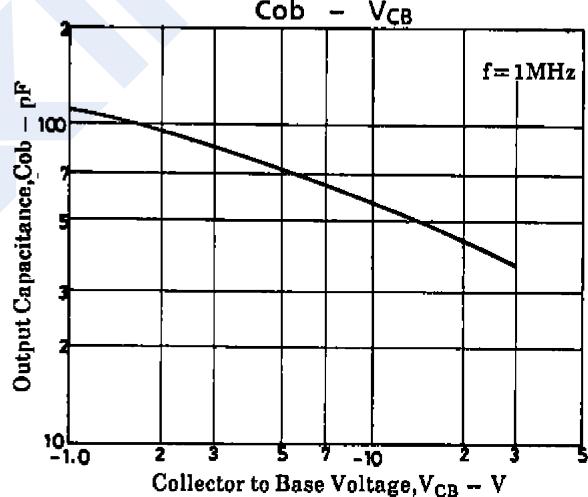
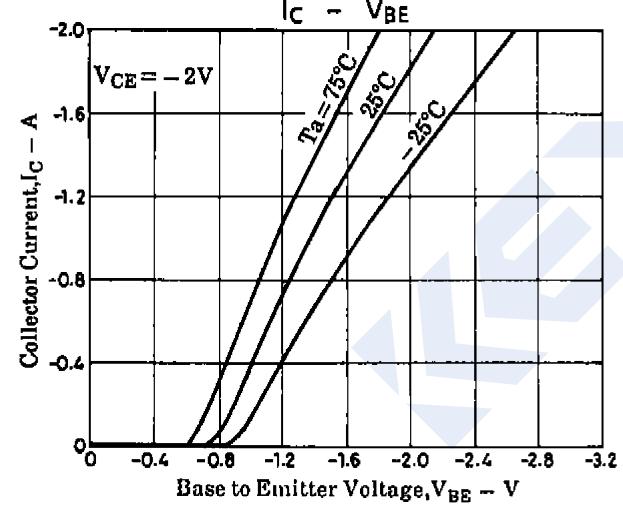
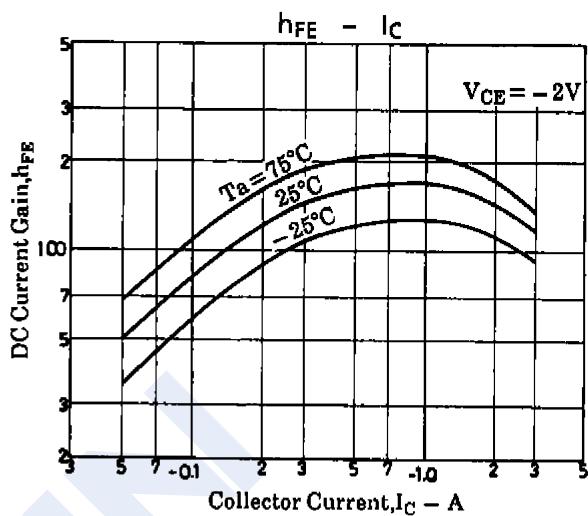
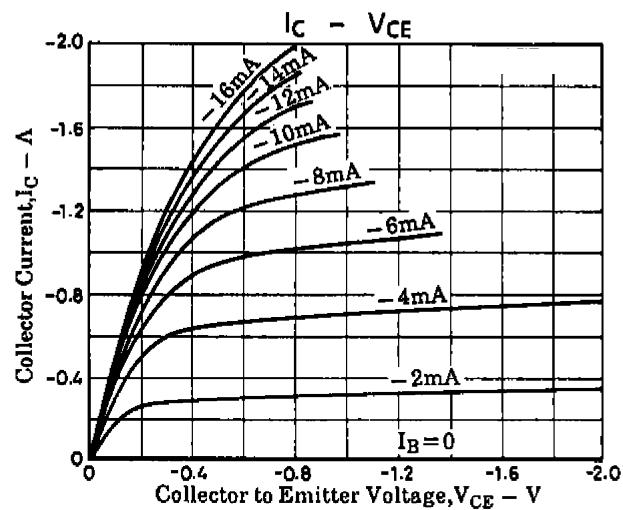
Marking

BN\_F

## PNP Transistors

2SB1394-HF

## ■ Typical Characteristics



**PNP Transistors****2SB1394-HF**

## ■ Typical Characteristics

